


**RoHS  
COMPLIANCE**


## Features

- ◊ Low power loss, high efficiency
- ◊ High current capability, Low forward voltage drop.
- ◊ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ◊ High surge current capability
- ◊ Qualified as per AEC-Q101
- ◊ Guard-ring for transient protection
- ◊ For use in low voltage, high frequency inverter, freewheeling, and polarity protection application
- ◊ High temperature soldering guaranteed: 260°C/10S/.375"(9.5mm) lead lengths 5 lbs tension

## Mechanical Data

- ◊ Case: TO-220AB
- ◊ Terminals: Pure tin plated leads, solderable per MIL-STD-202, Method 208 guaranteed
- ◊ Polarity: As marked
- ◊ Weight: 1.88 grams
- ◊ Mounting Torque: 5 in-lbs. max.
- ◊ Mounting position: Any

## Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

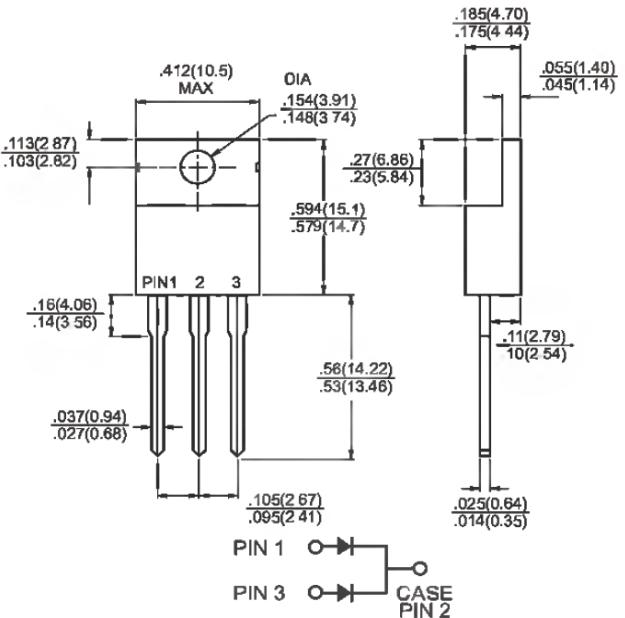
Parameter	Symbol	MBR10L100CT		Unit
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	100		V
Maximum RMS Voltage	V <sub>RMS</sub>	70		V
Maximum DC blocking voltage	V <sub>DC</sub>	100		V
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>	10		A
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	I <sub>F(RMS)</sub>	10		A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	I <sub>FSM</sub>	120		A
Peak Repetitive Reverse Surge Current ( Note 1)	I <sub>RRM</sub>	1		A
Maximum Instantaneous Forward Voltage (Pulse test: tp=300us, δ < 1%) @ 5A / Ta=25°C @ 5A / Ta=125°C @ 10A / Ta=25°C @ 10A / Ta=125°C	V <sub>F</sub>	TYP. 0.73 0.59 0.82 0.66	Max. 0.76 0.65 0.85 0.71	V
Maximum Reverse Current (Pulse test: tp=300us, δ < 1%) Ta=25 °C Ta=125 °C	I <sub>R</sub>	TYP. 0.3 0.5	Max. 20 15	uA mA
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10,000		V/uS
Typical Junction Capacitance (Note 2)	C <sub>j</sub>	185		pF
Typical Thermal Resistance (Note 3)	R <sub>θJC</sub>	2.8		°C/W
Operating Temperature Range	T <sub>J</sub>	-55 to + 150		°C
Storage Temperature Range	T <sub>STG</sub>	-55 to + 150		°C

Note1: 2.0uS Pulse Width, F=1.0KHz, Continues 10 cycles

Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

Note3: Mount on Heatsink Size of 4" x 6" x 0.25" Al-Plate

**MBR10L100CT**  
Low VF Isolated 10.0Amp Schottky Barrier Rectifier  
TO-220AB



**Dimensions in inches and (millimeters)**



**Marking Diagram**

MBR10LXXXCT = Specific Device Code  
 G = Green Compound  
 Y = Year Code  
 WW = Work Week Code

## RATINGS AND CHARACTERISTIC CURVES (MBR10L100CT)

Fig.1 Maximum Forward Current Derating Curve

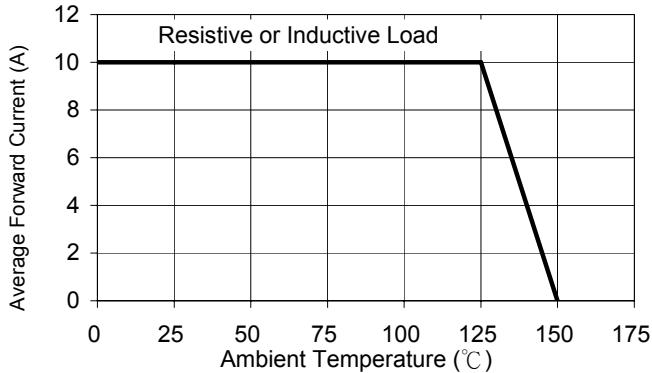


Fig. 2 Maximum Forward Surge Current

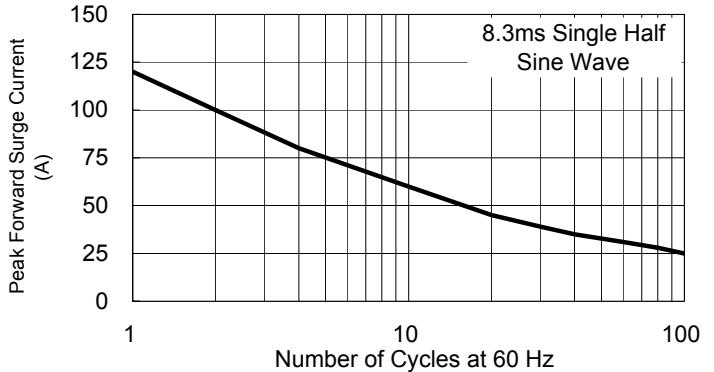


Fig. 3 Typical Forward Characteristics

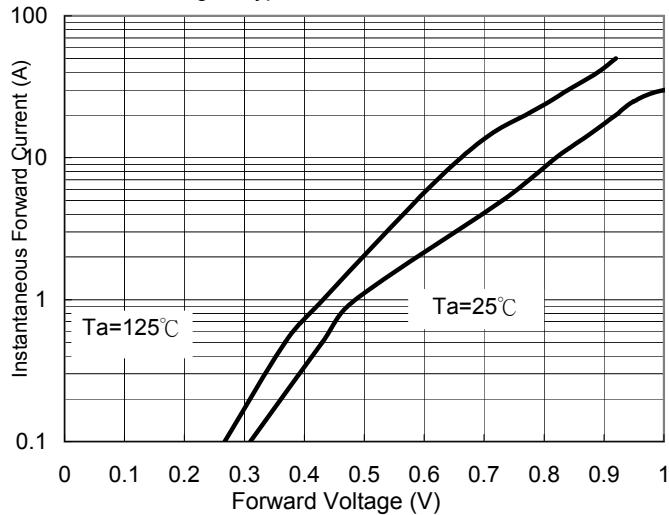


Fig. 4 Typical Reverse Characteristics

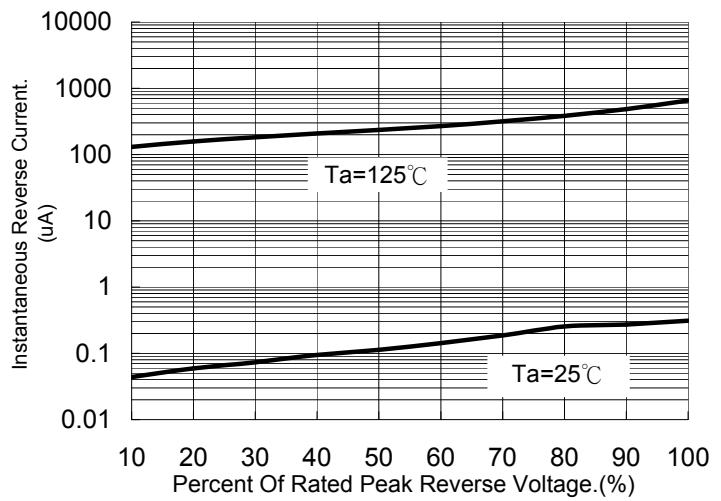


Fig. 5 Typical Junction Capacitance

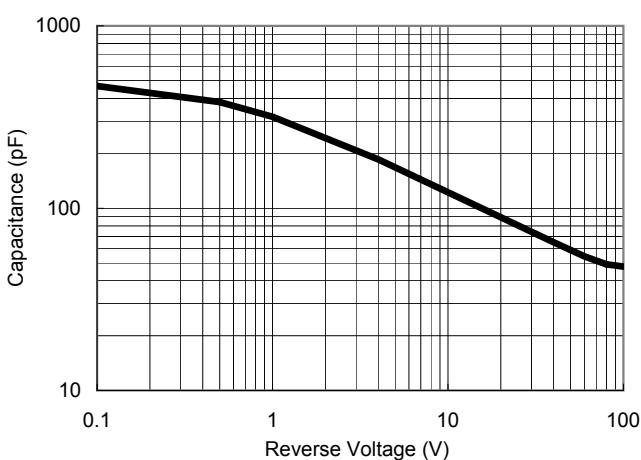


Fig. 6 Typical Transient Thermal Impedance

